PAGE 1/8 * RCVD AT 2/13/2004 1:37:36 PM [Eastern Standard Time] * SVR:USPTO-EFXRF-1/2 * DNIS:8729306 * CSID:518 449 0047 * DURATION (mm-55):02-14

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Applicant:

Letavic et al.

Examiner:

Lewis, M.

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Title:

DUAL GATE OXIDE HIGH-VOLTAGE SEMICONDUCTOR DEVICE

COMMISSIONER FOR PATENTS

DESTINATION PHONE NUMBER:

703-872-9306

Transmitted herewith is:

Amendment in 7 pages

in the above identified application.

- No additional fee is required.
- The Commissioner is hereby authorized to charge and credit Deposit Account No. 500999 as described below.
 - Credit any overpayment.
 - Charge any additional fee required.

n A. Merecki, Reg. No. 35,812

DATE: February 13, 2004

CERTIFICATION OF FACSIMILE TRANSMISSION

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